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|---|--|-------------------------------------|
|  | <h2 style="color: orange;">RAQ045P01TCR</h2>   |                                     |
|   | <b>Hersteller-Teilenummer:</b>   | <a href="#">RAQ045P01TCR</a>        |
|  | <b>Hersteller / Marke:</b>   | <a href="#">LAPIS Semiconductor</a> |
|   | <b>Teil der Beschreibung:</b>  | MOSFET P-CH 12V 4.5A TUMT6          |
| <b>Datenblätter:</b>  |  <a href="#">RAQ045P01TCR.pdf</a> |                                     |
| <b>RoHs Status:</b>   | Bleifrei / RoHS-konform  |                                     |
| <b>Lagerzustand:</b>  | New original, 3000 pcs Stock Available.  |                                     |
| <b>Liefern von:</b>   | Hong Kong  |                                     |
| <b>Versandweg:</b>  | DHL/Fedex/TNT/UPS/EMS  |                                     |
| <p>Image may be representation.<br/>See specs for product details.</p>            |  |                                     |

### Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | <a href="#">RAQ045P01TCR</a>  |
| Hersteller                                       | <a href="#">LAPIS Semiconductor</a>                                 |
| Beschreibung                                     | MOSFET P-CH 12V 4.5A TUMT6  |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a> |
| Teilstatus                                       | 3000 pcs Stock  |
| Serie  | -   |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Betriebstemperatur                               | 150 °C (TJ)   |
| Befestigungsart                                  | Surface Mount   |
| Verpackung / Gehäuse                             | SOT-23-6 Thin, TSOT-23-6  |
| Supplier Device-Gehäuse                          | TSMT6 (SC-95)   |
| Verlustleistung (max)                            | 600mW (Ta)  |
| Typ FET  | P-Channel   |
| FET-Merkmal                                      | -   |
| Drain-Source-Spannung (Vdss)                     | 12V   |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 4.5A (Ta)   |
| Rds On (Max) @ Id, Vgs                           | 30 mOhm @ 4.5A, 4.5V  |
| VGS (th) (Max) @ Id                              | 1V @ 1mA  |
| Gate Charge (Qg) (Max) @ Vgs                     | 40nC @ 4.5V   |
| Eingabekapazität (Ciss) (Max) @ Vds              | 4200pF @ 6V   |
| Antriebsspannung (Max Rds On, Min Rds On)        | 1.5V, 4.5V  |
| Vgs (Max)  | -8V   |
| Verpackung                                       | Tape & Reel (TR)  |

RAQ045P01TCR ist neu im Original, Suche RAQ045P01TCR Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RAQ045P01TCR LAPIS Semiconductor mit Garantie und Vertrauen. Anfrage RAQ045P01TCR: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|   |  |   |  |
|---|--|---|--|
|  <p><b>SI8424CDB-T1-E1</b><br/>Vishay / Siliconix<br/>MOSFET N-CH 8V MICROFOOT</p> |  <p><b>SQ2325ES-T1_GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 150V 840MA<br/>TO236</p>  |  <p><b>RAQ045P01 TR</b><br/>ROHM<br/>RAQ045P01 TR ROHM</p>                    |  <p><b>RAQ045P01MGTCR</b><br/>LAPIS Semiconductor<br/>1.5V DRIVE PCH MOSFET</p> |
|  <p><b>IXTN60N50L2</b><br/>IXYS Corporation<br/>MOSFET N-CH 500V 53A SOT-227</p>   |  <p><b>IPC30S2SN08NX2MA1</b><br/>International Rectifier (Infineon Technologies)<br/>MV POWER MOS</p> |  <p><b>IXFT70N15</b><br/>IXYS Corporation<br/>MOSFET N-CH 150V 70A TO-268</p> |  <p><b>RAQ045P01</b><br/>ROHM<br/>RAQ045P01 ROHM</p>                            |

### heiße Teile

Mehr

|                 |                    |                 |                    |                   |
|-----------------|--------------------|-----------------|--------------------|-------------------|
| 08055A5R5CAT2A  | 12065A120GAT2A     | 2-1734255-1     | AC575V 75A-2       | AIC1653GVTR       |
| APA3010QGC-DC2  | APL5156KAI-TU      | BL8509-293DCRM  | BS62LV4007SC-70    | CC0402KRX7R6BB473 |
| CFS-0502MC      | CP0402A0836CNTR    | CP2124ST-A2     | F3L150R07W2E3-B11  | FGH80N60FDTU      |
| FH8065301685597 | GRM155R71C473JA01D | ICL3221EIVZ-T   | IDT74SSTVF16859PAG | INA126EA/250      |
| IRFR420PBF      | ISL60002BIH320Z-TK | LC1207CB3TR28   | LM4936MHX/NOPB     | LMH6551MMX        |
| MAMK2520T2R2M   | MAX3483ESA+T       | MAX487EEPA+     | MIC1815-10UY       | MRF24WG0-I/VG     |
| NE722S01-T1     | PB05E-05-A         | PI6C2308A-1HL   | RAQ045P01          | SBRT20U50SLPQ     |
| SC431LCSK-.5TRT | SC4808AIMSTRT      | SI7660CJ        | SKKR300/0.2-BVR    | SLVG2.8.TCT       |
| SMBT3904PNH6327 | SML4756A-E3/61     | SN74LS321N      | SN74LV14AD         | STM6778TGWB6F     |
| UDZWTE-1733B    | UESD5V0W300T4R     | UWR-12/1250-D5A | WS05-4R2P          | WSP25122L000FEA   |

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HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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